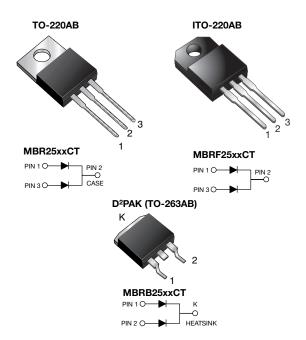


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Vishay General Semiconductor

RoHS

Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 12.5 A			
V_{RRM}	35 V, 45 V			
I _{FSM}	150 A			
V_{F}	0.73 V at 30 A			
T _J max.	150 °C			
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)			
Circuit configuration	Common cathode			

FEATURES

Power pack



- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D2PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3_A
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB) Epoxy meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 gualified Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR2535CT	MBR2545CT	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	35	45		
Working peak reverse voltage		V_{RWM}	35	45	V	
Maximum DC blocking voltage		V_{DC}	35	45]	
Maximum average forward rectified current at $T_C = 130 ^{\circ} C$	total device		25		A	
	per diode	I _{F(AV)}	12.5			
Peak forward surge current 8.3 ms single half sine-wave s rated load per diode	superimposed on	I _{FSM}	150			
Peak repetitive reverse surge current per diode at $t_p = 2 \mu s$, 1 kHz		I _{RRM}	1.0		A	
Peak non-repetitive reverse energy (8/20 μs waveform) per diode		E _{RSM}	2	25	mJ	
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k Ω		V _C	25		kV	
Voltage rate of change (rated V _R)		dV/dt	10	000	V/µs	
Operating junction temperature range		TJ	-65 to +150		°C	
Storage temperature range		T _{STG}	-65 to	o +175		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	15	500	V	



MBR25xxCT, MBRF25xxCT, MBRB25xxCT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR2535CT	MBR2545CT	UNIT		
Maximum instantaneous forward voltage per diode	I _F = 15 A	T _C = 25 °C	V _F ⁽¹⁾	-				
		T _C = 125 °C		-		V		
	I _F = 30 A	T _C = 25 °C		0.82		ľ		
		T _C = 125 °C		0.73				
Maximum instantaneous reverse current at blocking voltage per diode		T _C = 25 °C	I _R ⁽¹⁾	0.2		mA		
			IR '''	4	0			

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.5	4.5	1.5	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR2545CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB2545CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB2545CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR2545CT-E3/4W	1.85	4W	50/tube	Tube		
TO-220AB	MBR2545CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CTHE3/45 (1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB2545CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB2545CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		
TO-263AB	MBRB2545CTHE3_A/P (1)	1.35	Р	50/tube	Tube		
TO-263AB	MBRB2545CTHE3_A/I (1)	1.35	I	800/reel	Tape and reel		

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

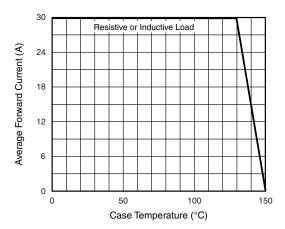


Fig. 1 - Forward Current Derating Curve

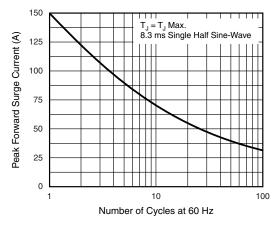


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

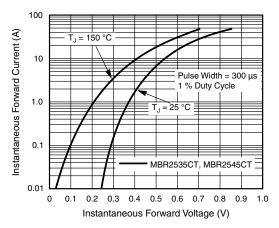


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

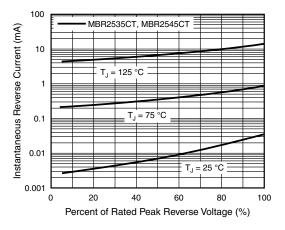


Fig. 4 - Typical Reverse Characteristics Per Diode

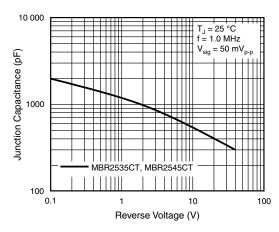


Fig. 5 - Typical Junction Capacitance Per Diode

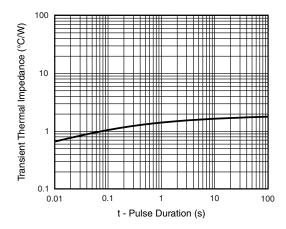


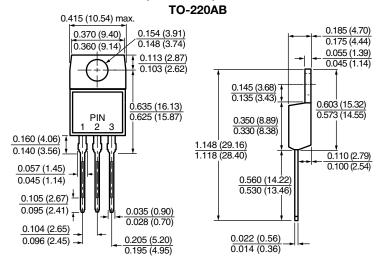
Fig. 6 - Typical Transient Thermal Impedance Per Diode

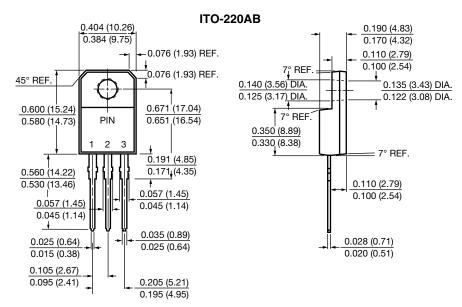




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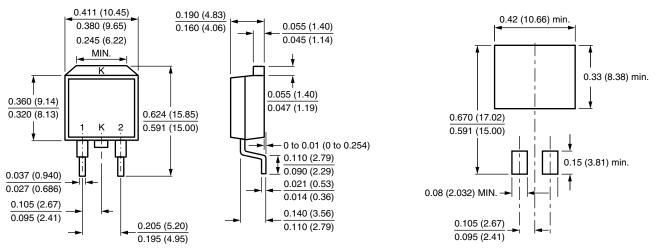
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





D²PAK (TO-263AB)

Mounting Pad Layout



Revision: 14-Jun-17 4 Document Number: 88675

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